MOSPEC

SRF2030CE Thru SRF2060CE

Switchmode
Full Plastic Dual Schottky Barrier Power Rectifiers

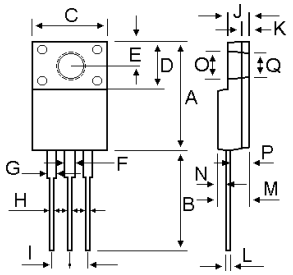
Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

* Low Forward Voltage.
* Low Switching noise.
* High Current Capacity
* Guarantee Reverse Avalanche.
* Guard-Ring for Stress Protection.
* Low Power Loss & High efficiency.
* 150℃ Operating Junction Temperature
* Low Stored Charge Majority Carrier Conduction.
* Plastic Material used Carries Underwriters Laboratory

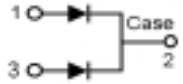
SCHOTTKY BARRIER RECTIFIERS

20 AMPERES
30-60 VOLTS

ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	15.05	15.15
B	13.35	13.45
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
P	2.65	2.75
O	3.35	3.45
Q	3.15	3.25



Common cathode
Suffix "C"

MAXIMUM RATINGS

Characteristic	Symbol	SRF20						Unit
		30CE	35CE	40CE	45CE	50CE	60CE	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	30	35	40	45	50	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	25	28	32	35	42	V
Average Rectifier Forward Current Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	10 20						A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	20						A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	200						A
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150						℃

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	SRF20						Unit
		30CE	35CE	40CE	45CE	50CE	60CE	
Maximum Instantaneous Forward Voltage (I_F =10 Amp T_C = 25℃) (I_F =10 Amp T_C = 125℃)	V_F	0.57 0.48				0.65 0.57		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	0.5 30						mA

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FIG-1 FORWARD CURRENT DERATING CURVE

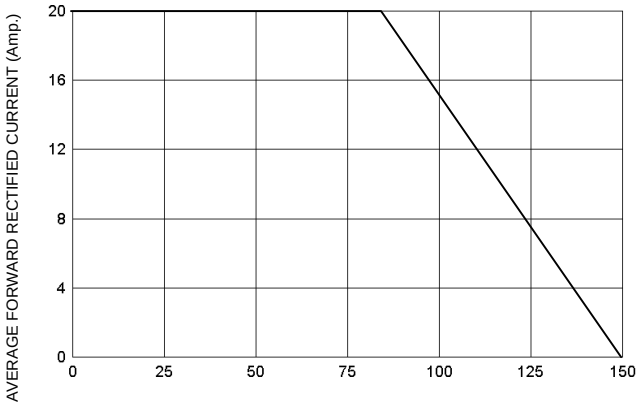


FIG-2 TYPICAL FORWARD CHARACTERISITICS

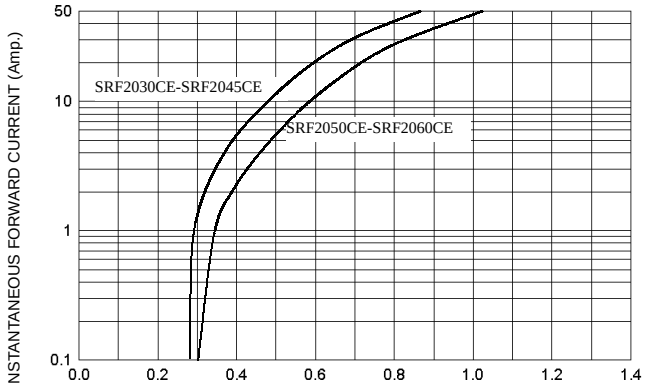


FIG-3 TYPICAL REVERSE CHARACTERISTICS

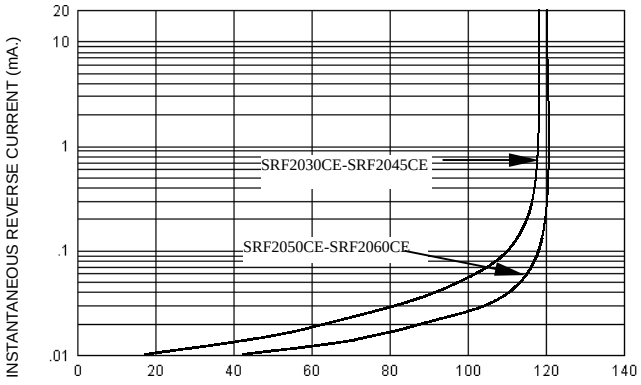


FIG-4 TYPICAL JUNCTION CAPACITANCE

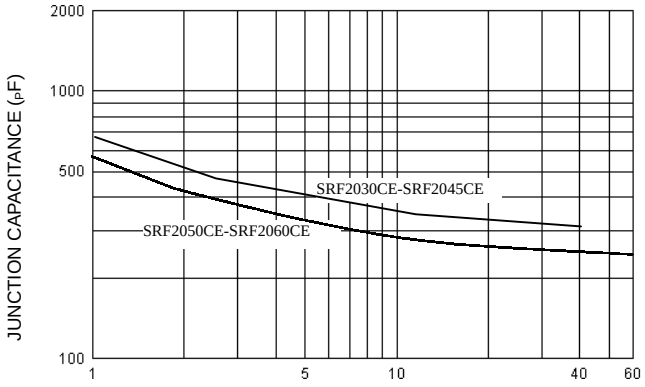
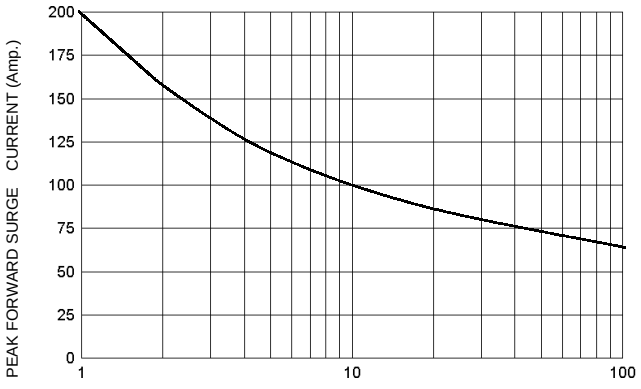


FIG-5 PEAK FORWARD SURGE CURRENT



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